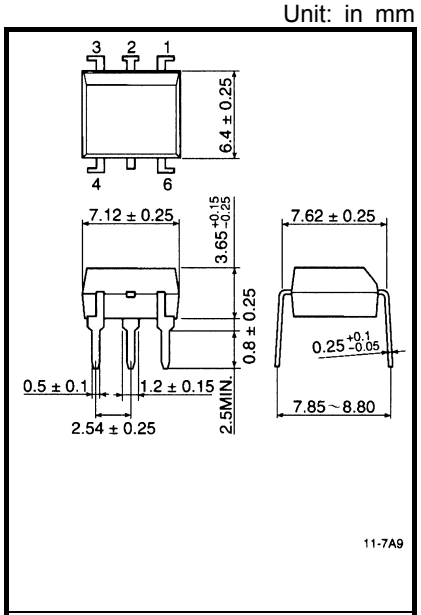
TOSHIBA PHOTOCOUPLER GaAlAs IRED & PHOTO-TRIAC

TLP3064(S)

OFFICE MACHINE
HOUSEHOLD USE EQUIPMENT
TRIAC DRIVER
SOLID STATE RELAY

Unit: in mm



JEDEC	
TOSHIBA	11-7A9

Weight: 0.39 g

The TOSHIBA TLP3064(S) consists of a zero voltage crossing turn-on photo-triac optically coupled to a GaAlAs infrared emitting diode in a six lead plastic DIP package.

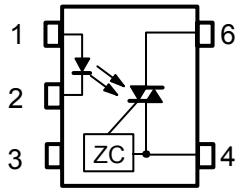
- Peak Off-State Voltage : 600 V(Min)
- Trigger LED Current : 3 mA(Max)
- On-State Current : 100 mA(Max)
- Isolation Voltage : 5000 Vrms(Min)
- UL Recognized : UL1577,File No.E67349
- SEMKO Approved : SS EN60065
  SS EN60950, File No.9841113
- BSI Approved : BS EN60065, File No.8385
  BS EN60950, File No.8386
- Option (D4) type
  VDE approved: DIN EN60747-5-2
  Approved No. 40009302
  Maximum operating insulation voltage: 890 V_{PK}
  Highest permissible over voltage: 8000 V_{PK}

(Note):When a EN60747-5-2 approved type is needed, please designate the "Option (D4)"

Construction Mechanical Rating

	7.62 mm pitch Standard Type	10.16 mm pitch TLPxxxxF Type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.5 mm (Min)	0.5 mm (Min)

Pin Configuration (top view)



1: Anode
2: Cathode
3: N.C.
4:Terminal 1
6:Terminal 2

ZC:Zero-cross Circuit

Absolute Maximum Ratings (Ta = 25°C)

	CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current		I_F	30	mA
	Forward Current Derating (Ta ≥ 25°C)		ΔI_F /°C	−0.3	mA /°C
	Peak Forward Current (100 μs pulse, 100 pps)		I_{FP}	1	A
	Reverse Voltage		V_R	5	V
	Junction Temperature		Tj	125	°C
DETECTOR	Off-State Output Terminal Voltage		V_{DRM}	600	V
	On-State RMS Current	Ta = 25°C	$I_{T(RMS)}$	100	mA
		Ta = 70°C		50	
	On-State Current Derating (Ta ≥ 25°C)		ΔI_T/°C	-1.1	mA /°C
	Peak On-State Current (100 μs pulse, 120 pps)		I_{TP}	2	A
	Peak Nonrepetitive Surge Current (Pw = 10 ms, DC = 10%)		I_{TSM}	1.2	A
	Junction Temperature		T_j	115	°C
Storage Temperature Range			T_{stg}	−55 to 150	°C
Operating Temperature Range			T_{opr}	−40 to 100	°C
Lead Soldering Temperature (10 s)			T_{sol}	260	°C
Isolation Voltage (AC, 1 min., R.H.≤60%)		(Note 2)	BV_S	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 2) Device considered a two terminal device:Pins1, 2 and 3 shorted together and pin 4 and pin 6 shorted together.

Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{AC}	—	—	240	V_{ac}
Forward Current	I_F	4.5	6	7.5	mA
Peak On-State Current	I_{TP}	—	—	1	A
Operating Temperature	T_{opr}	−10	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

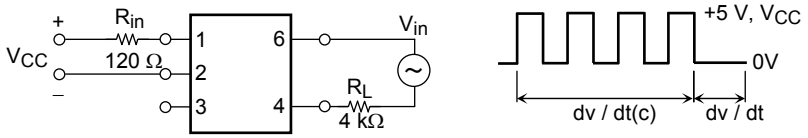
Individual Electrical Characteristics (Ta=25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	I_F = 10 mA	1.2	1.4	1.7	V
	Reverse Current	I_R	V_R = 3 V	—	—	10	μA
	Capacitance	C_T	V = 0, f = 1 MHz	—	30	—	pF
DETECTOR	Peak Off-State Current	I_{DRM}	V_{DRM} = 600 V	—	10	1000	nA
	Peak On-State Voltage	V_{TM}	I_{TM} = 100 mA	—	—	3.0	V
	Holding Current	I_H	—	—	0.6	—	mA
	Critical Rate of Rise of Off-State Voltage	dv / dt	Vin = 240 Vrms, Ta = 85°C (Fig.1)	200	500	—	V/μs
	Critical Rate of Rise of Commutating Voltage	dv / dt(c)	Vin = 60 Vrms, I_T = 15 mA (Fig.1)	—	0.2	—	V/μs

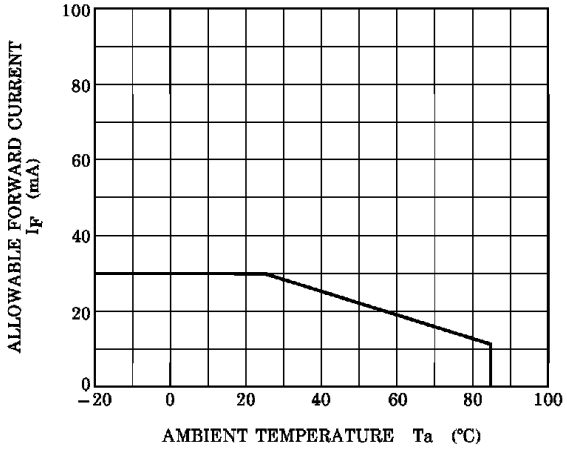
Coupled Electrical Characteristics (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	V_T = 3 V ,Resistive Load	—	—	3	mA
Inhibit Voltage	V_{IH}	I_F = Rated I_{FT}	—	—	50	V
Leakage in Inhibited State	I_{IH}	I_F = Rated I_{FT} , V_T = Rated V_{DRM}	—	—	600	μA
Capacitance (Input to Output)	C_S	V_S =0, f=1 MHz	—	0.8	—	pF
Isolation Resistance	R_S	V_S = 500 V, R.H.≤60%	1×10^{12}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	5000	—	—	Vrms
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

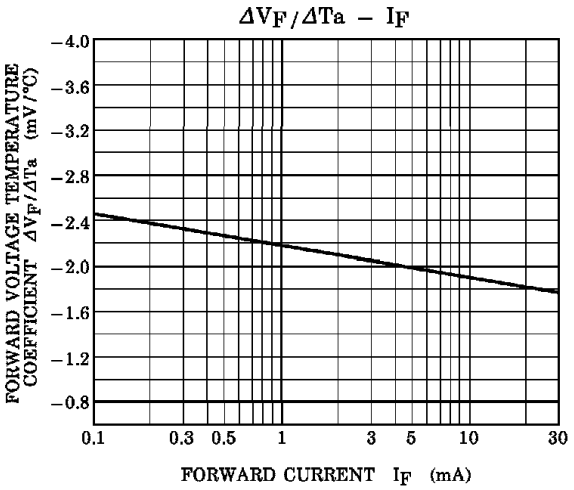
Fig. 1 dv / dt test circuit



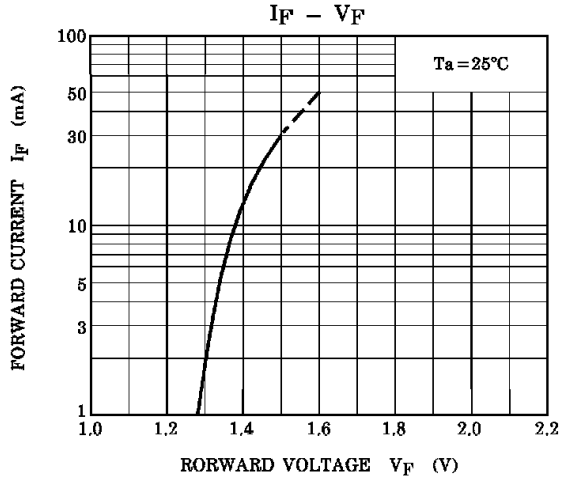
I_F – Ta



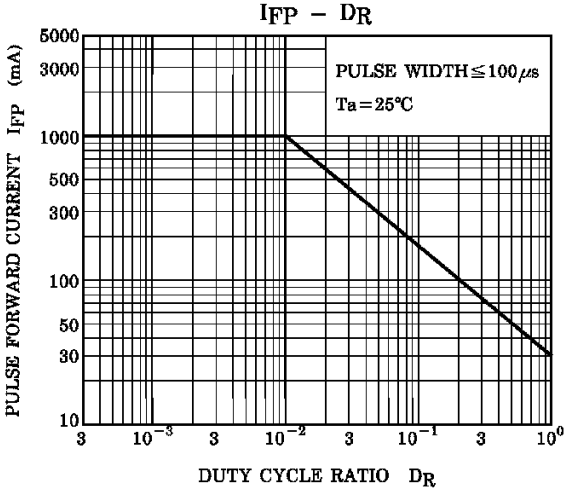
$\Delta V_F / \Delta Ta$ – I_F



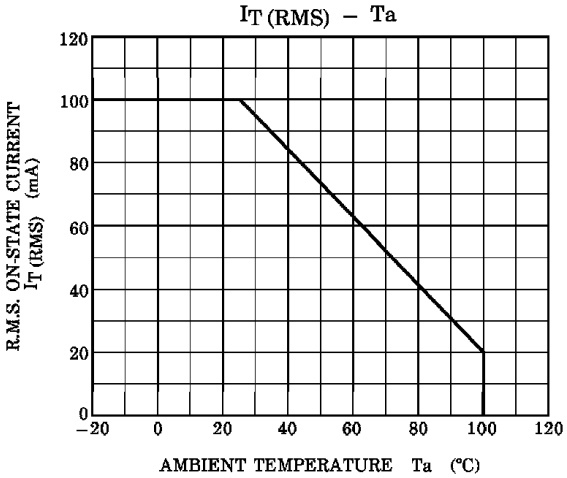
I_F – V_F



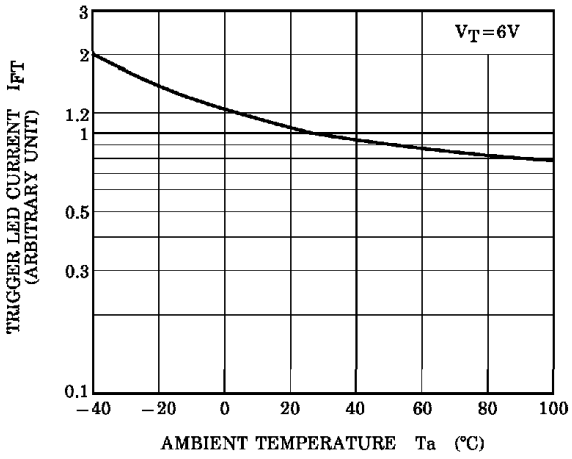
I_{FP} – D_R



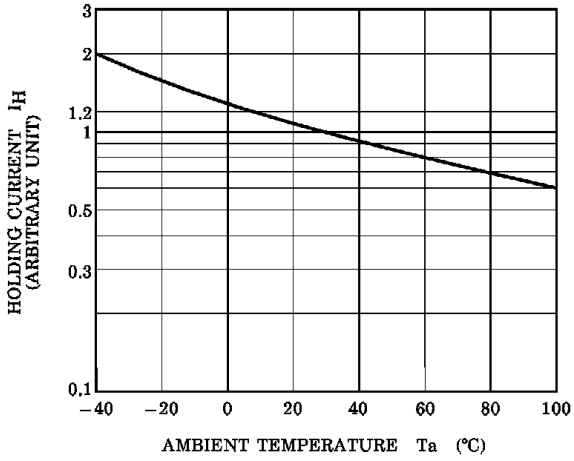
$I_{T\,(RMS)}$ – Ta



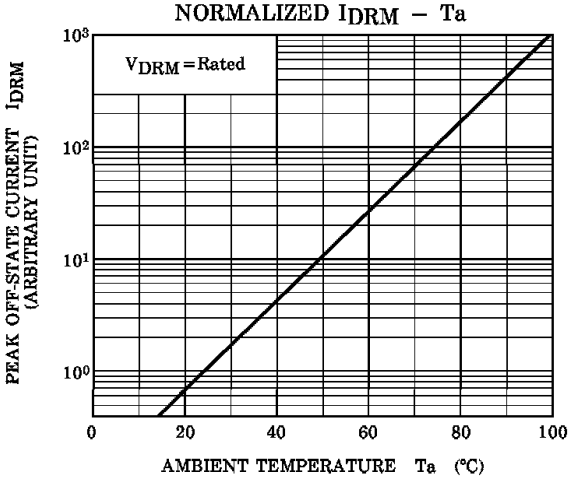
NORMALIZED I_{FT} – Ta



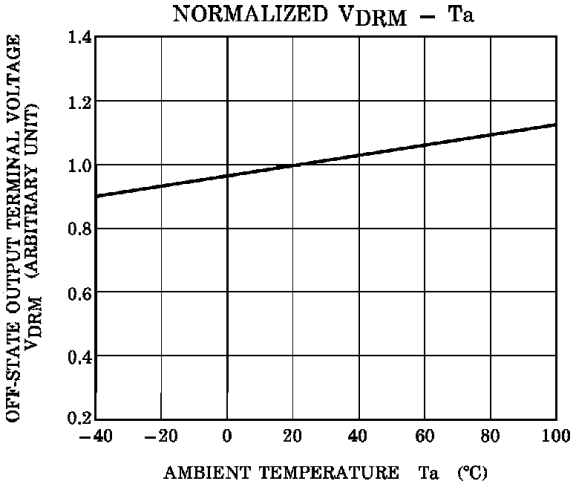
NORMALIZED I_H – Ta



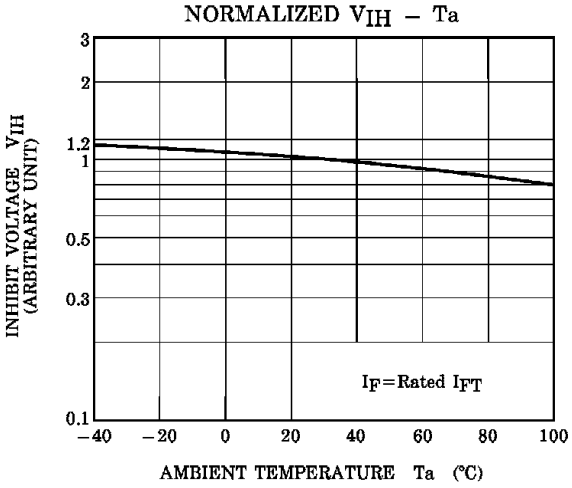
NORMALIZED I_{DRM} – Ta



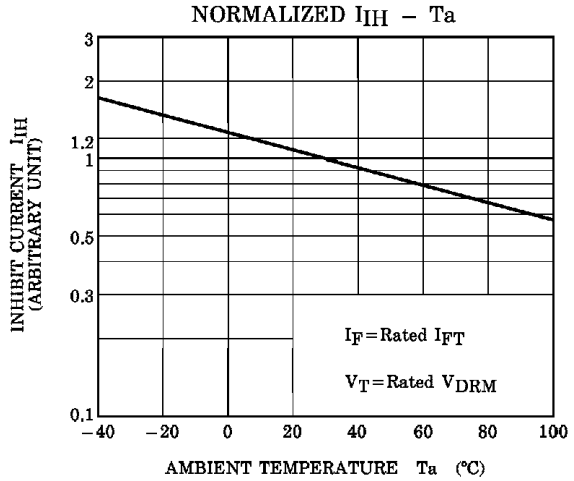
NORMALIZED V_{DRM} – Ta



NORMALIZED V_{IH} – Ta



NORMALIZED I_{IH} – Ta



RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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